NSN 5961-01-212-7310

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-212-7310 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 0.700 inches **Overall Diameter:** 0.085 inches **End Application:** Satellite communications set, an/wsc- (v) 9 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 regulator voltage **Current Rating Per Characteristic:** 50.00 milliamperes dc current in reverse breakdown region and 600.00 milliamperes source current **Power Rating Per Characteristic:** 3.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig:

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